

## N-Channel Power MOSFET

600V, 38A, 99mΩ

### FEATURES

- Super-Junction technology
- High performance, small  $R_{DS(ON)} * Q_g$  figure of merit (FOM)
- High ruggedness performance
- 100% UIS and  $R_g$  tested
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

| KEY PERFORMANCE PARAMETERS |       |      |
|----------------------------|-------|------|
| PARAMETER                  | VALUE | UNIT |
| $V_{DS}$                   | 600   | V    |
| $R_{DS(on)}$ (max)         | 99    | mΩ   |
| $Q_g$                      | 62    | nC   |

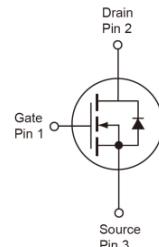
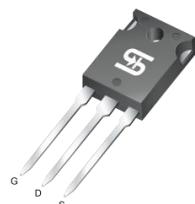
### APPLICATIONS

- PFC stage
- Server/Telecom Power
- Charging Station
- Inverter
- Power Supply


**RoHS**  
COMPLIANT

**HALOGEN  
FREE**

TO-247



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETER  | SYMBOL         | LIMIT        | UNIT |
|--|----------------|--------------|------|
| Drain-Source Voltage                               | $V_{DS}$       | 600          | V    |
| Gate-Source Voltage                                | $V_{GS}$       | $\pm 30$     | V    |
| Continuous Drain Current <sup>(Note 1)</sup>       | $I_D$          | 38           | A    |
|  |                | 24           | A    |
| Pulsed Drain Current <sup>(Note 2)</sup>           | $I_{DM}$       | 114          | A    |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ | $P_D$          | 329          | W    |
| Single Pulse Avalanche Energy <sup>(Note 3)</sup>  | $E_{AS}$       | 784          | mJ   |
| Single Pulse Avalanche Current <sup>(Note 3)</sup> | $I_{AS}$       | 5.6          | A    |
| Operating Junction and Storage Temperature Range   | $T_J, T_{STG}$ | - 55 to +150 | °C   |

### THERMAL PERFORMANCE

| PARAMETER                              | SYMBOL          | LIMIT | UNIT |
|--|-----------------|-------|------|
| Junction to Case Thermal Resistance    | $R_{\Theta JC}$ | 0.38  | °C/W |
| Junction to Ambient Thermal Resistance | $R_{\Theta JA}$ | 42    | °C/W |

**Thermal Performance Note:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\Theta JA}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design.

| <b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted) |   |                     |            |            |            |                  |
|---|---|---------------------|------------|------------|------------|------------------|
| <b>PARAMETER</b>  | <b>CONDITIONS</b>   | <b>SYMBOL</b>       | <b>MIN</b> | <b>TYP</b> | <b>MAX</b> | <b>UNIT</b>      |
| <b>Static</b>   |   |                     |            |            |            |                  |
| Drain-Source Breakdown Voltage  | $V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$   | $BV_{DSS}$          | 600        | --         | --         | V                |
| Gate Threshold Voltage  | $V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$  | $V_{GS(\text{TH})}$ | 2          | 3          | 4          | V                |
| Gate Body Leakage   | $V_{GS} = \pm 30\text{V}$ , $V_{DS} = 0\text{V}$  | $I_{GSS}$           | --         | --         | $\pm 100$  | nA               |
| Zero Gate Voltage Drain Current   | $V_{DS} = 600\text{V}$ , $V_{GS} = 0\text{V}$   | $I_{DSS}$           | --         | --         | 1          | $\mu\text{A}$    |
| Drain-Source On-State Resistance<br><small>(Note 4)</small>                         | $V_{GS} = 10\text{V}$ , $I_D = 11.7\text{A}$  | $R_{DS(\text{on})}$ | --         | 86         | 99         | $\text{m}\Omega$ |
| <b>Dynamic</b> <small>(Note 5)</small>  |   |                     |            |            |            |                  |
| Total Gate Charge   | $V_{DS} = 480\text{V}$ , $I_D = 35\text{A}$ ,<br>$V_{GS} = 10\text{V}$                              | $Q_g$               | --         | 62         | --         | nC               |
| Gate-Source Charge  |   | $Q_{gs}$            | --         | 17         | --         |                  |
| Gate-Drain Charge   |   | $Q_{gd}$            | --         | 25         | --         |                  |
| Input Capacitance   | $V_{DS} = 100\text{V}$ , $V_{GS} = 0\text{V}$ ,<br>$f = 1.0\text{MHz}$                              | $C_{iss}$           | --         | 2587       | --         | pF               |
| Output Capacitance  |   | $C_{oss}$           | --         | 123        | --         |                  |
| Reverse Transfer Capacitance  |   | $C_{rss}$           | --         | 20         | --         |                  |
| Gate Resistance   | $f = 1.0\text{MHz}$   | $R_g$               | --         | 3.3        | 6.6        | $\Omega$         |
| <b>Switching</b> <small>(Note 6)</small>  |   |                     |            |            |            |                  |
| Turn-On Delay Time  | $V_{DD} = 300\text{V}$ ,<br>$R_{GEN} = 5\Omega$ ,<br>$I_D = 17.5\text{A}$ , $V_{GS} = 10\text{V}$ , | $t_{d(on)}$         | --         | 18         | --         | ns               |
| Turn-On Rise Time   |   | $t_r$               | --         | 24         | --         |                  |
| Turn-Off Delay Time   |   | $t_{d(off)}$        | --         | 87         | --         |                  |
| Turn-Off Fall Time  |   | $t_f$               | --         | 25         | --         |                  |
| <b>Source-Drain Diode</b>   |   |                     |            |            |            |                  |
| Body-Diode Continuous Forward Current   |   | $I_S$               | --         | --         | 38         | A                |
| Body-Diode Pulsed Current   |   | $I_{SM}$            | --         | --         | 114        | A                |
| Forward Voltage <small>(Note 4)</small>   | $I_S = 35\text{A}$ , $V_{GS} = 0\text{V}$   | $V_{SD}$            | --         | --         | 1.4        | V                |
| Reverse Recovery Time   | $I_S = 17.5\text{A}$<br>$dI_F/dt = 100\text{A}/\mu\text{s}$   | $t_{rr}$            | --         | 342        | --         | ns               |
| Reverse Recovery Charge   |   | $Q_{rr}$            | --         | 5.3        | --         | $\mu\text{C}$    |

**Notes:**

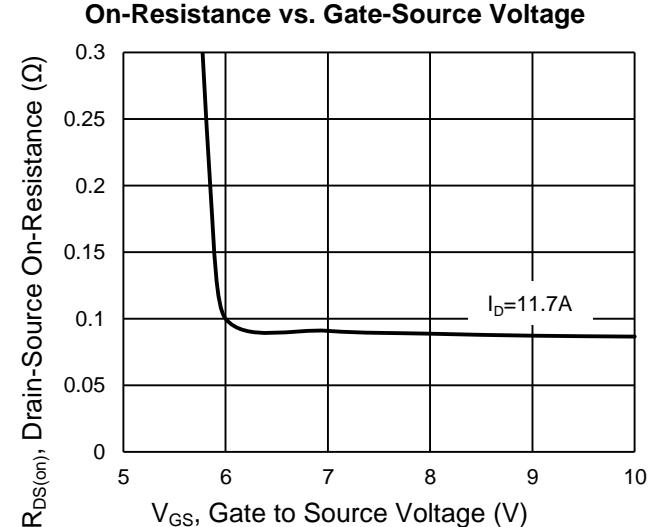
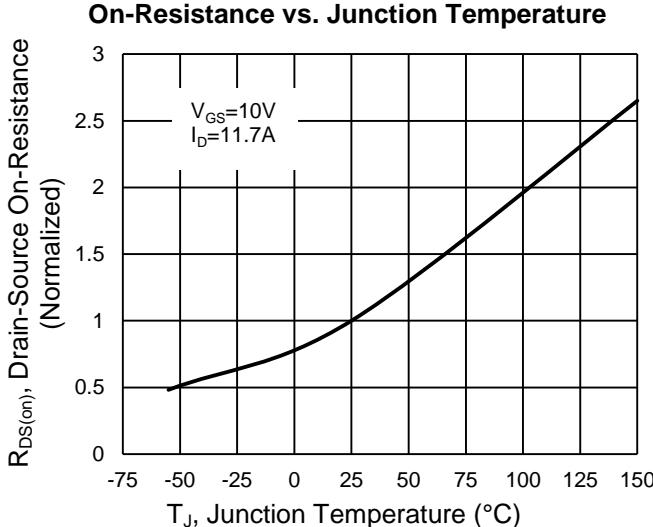
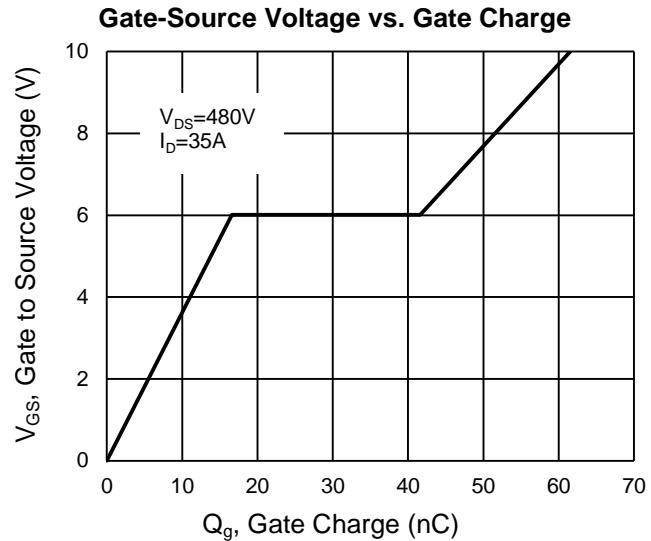
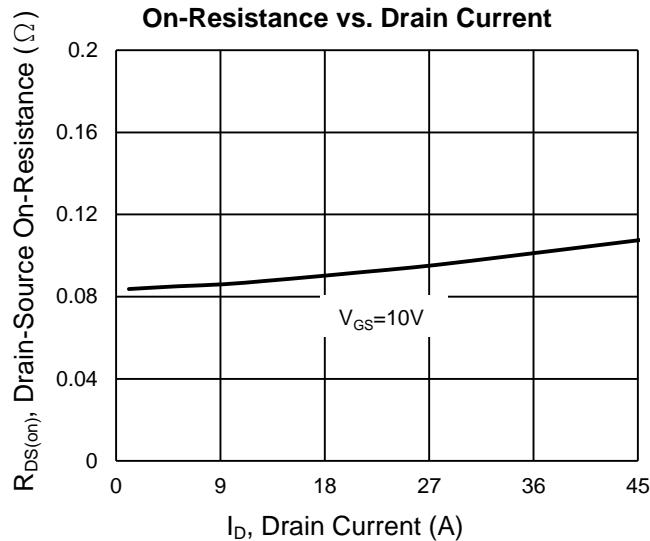
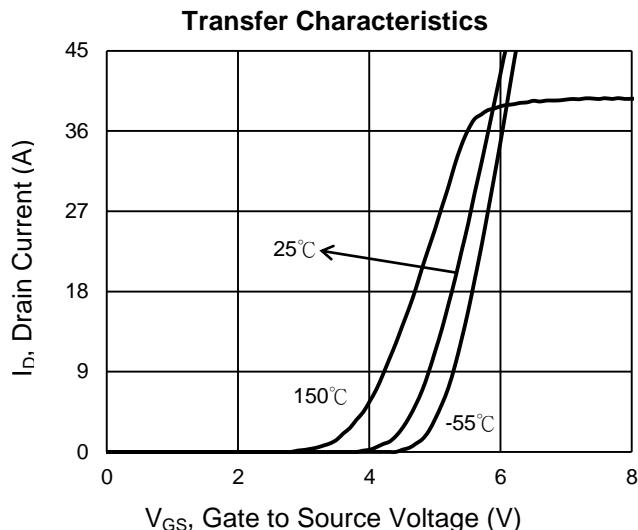
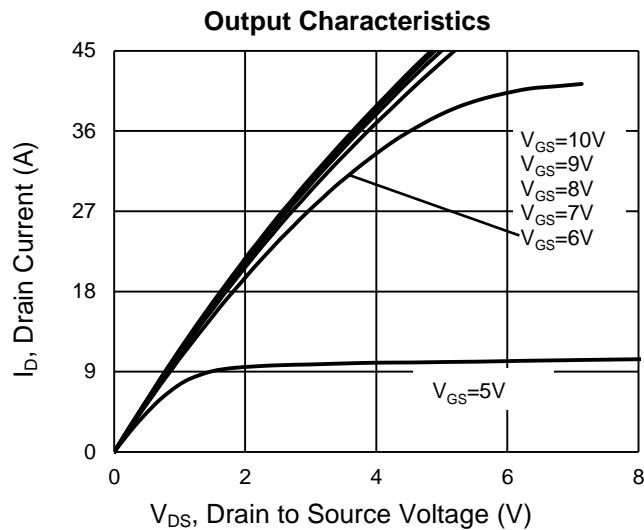
1. Current limited by package.
2. Pulse width limited by the maximum junction temperature.
3.  $L = 50\text{mH}$ ,  $I_{AS} = 5.6\text{A}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$
4. Pulse test:  $PW \leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

**ORDERING INFORMATION**

| <b>PART NO.</b>  | <b>PACKAGE</b> | <b>PACKING</b> |
|------------------|----------------|----------------|
| TSM60NB099PW C1G | TO-247         | 25pcs / Tube   |

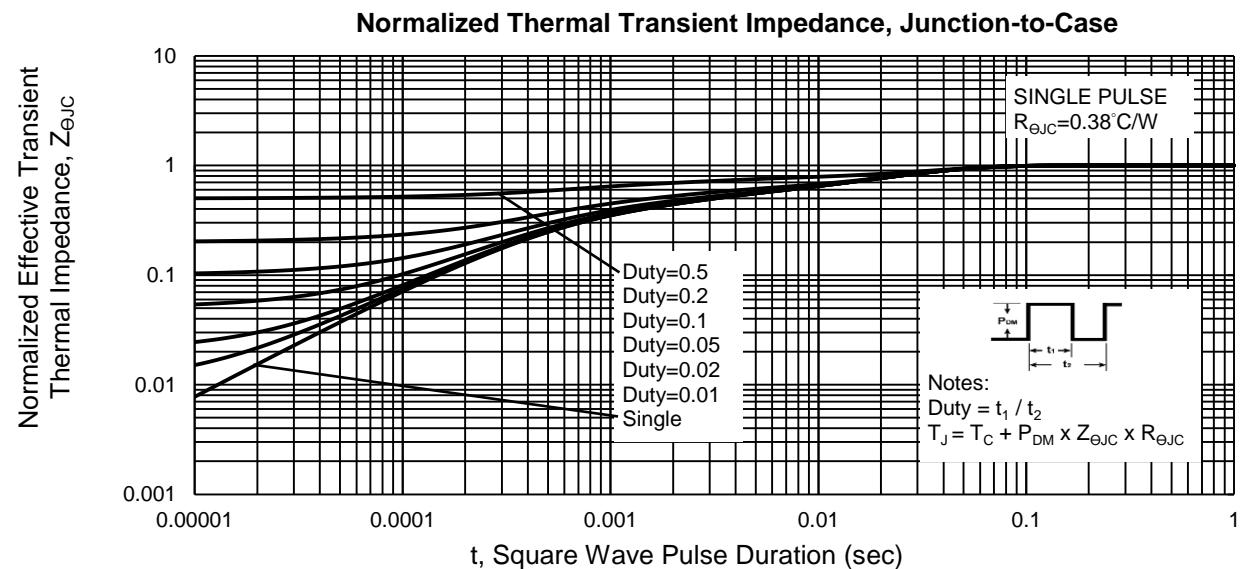
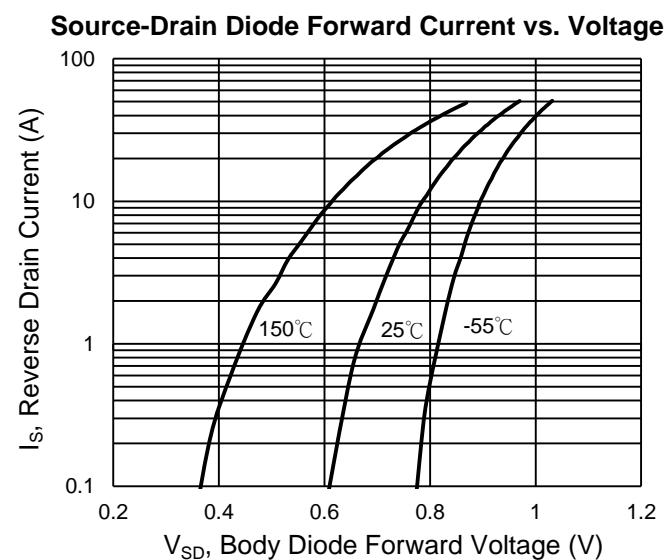
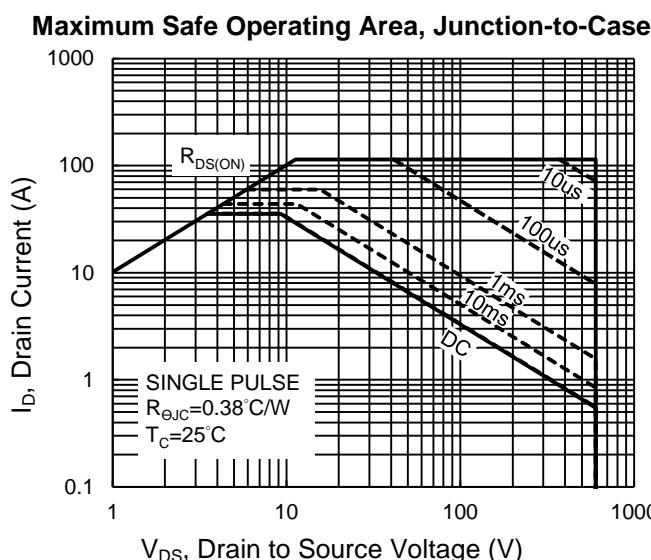
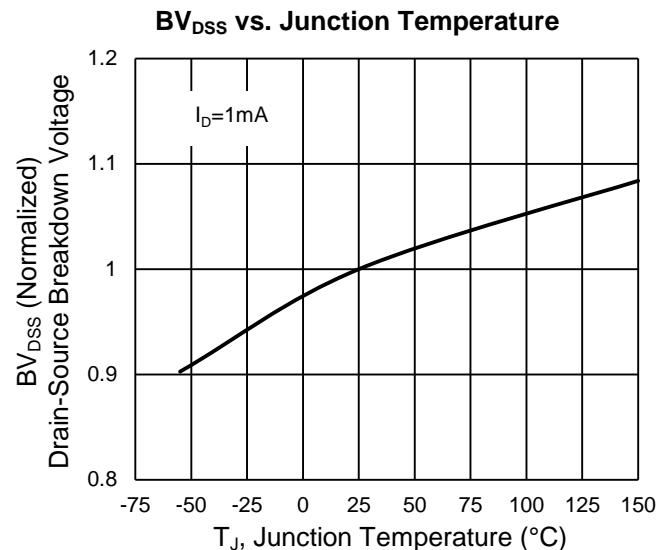
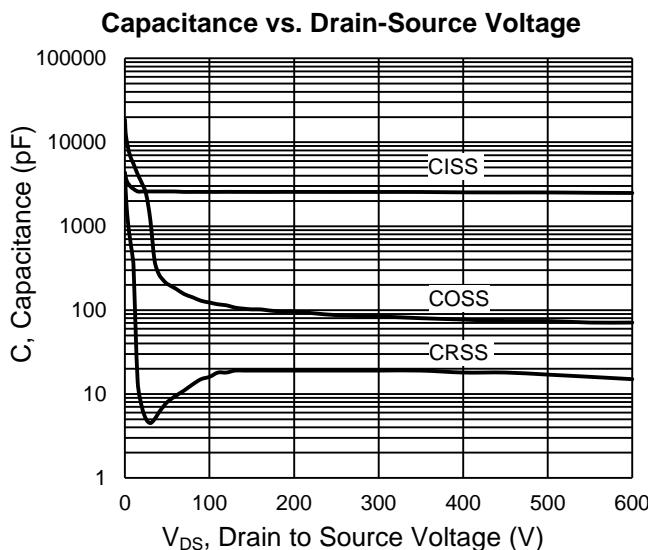
## CHARACTERISTICS CURVES

( $T_C = 25^\circ\text{C}$  unless otherwise noted)

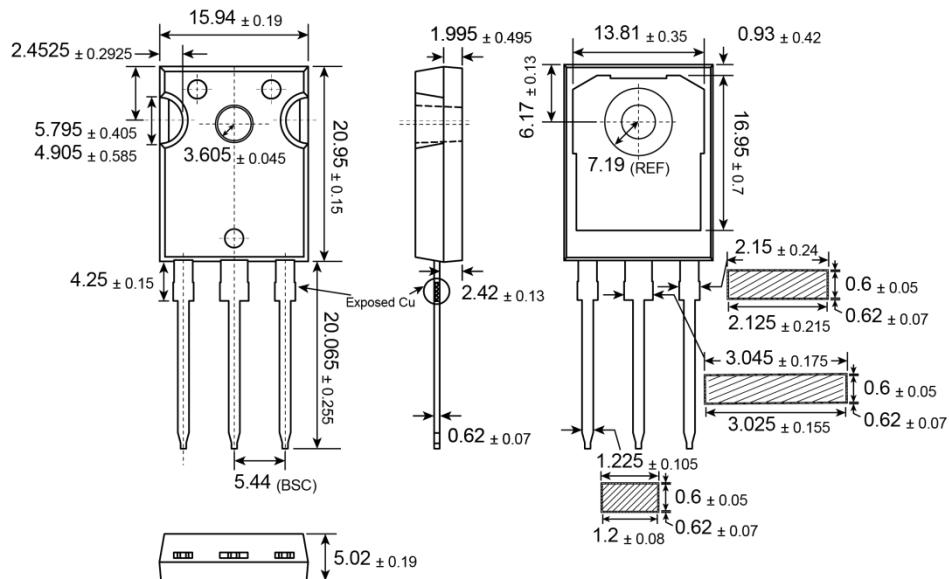


## CHARACTERISTICS CURVES

( $T_C = 25^\circ\text{C}$  unless otherwise noted)



**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

**TO-247**

**MARKING DIAGRAM**

**G** = Halogen Free

**Y** = Year Code

**WW** = Week Code (01~52)

**F** = Factory Code

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